

111. (Amended) An electroluminescence display device according to claim 109, wherein said first insulating layer has a planarized surface.

and F1, E2, C20
112. (Amended) An electroluminescence display device according to claim 109, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

E3
113. (Amended) An electroluminescence display device comprising:
at least one thin film transistor formed over a substrate;
a first insulating layer comprising silicon nitride formed over said thin film transistor;
a second insulating layer comprising organic resin formed over said first insulating layer;
a third insulating layer comprising DLC formed over said second insulating layer;
and F1
a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said third insulating layer.

and E4, F1
114. (Amended) An electroluminescence display device according to claim 113, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

E5, F1, F2
115. (Amended) An electroluminescence display device according to claim 113, wherein said second insulating layer has a planarized surface.

and E6, F1
116. (Amended) An electroluminescence display device according to claim 113, wherein said electroluminescence display device is incorporated into an electric

~~E6~~
apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

E7
117. (Amended) An electroluminescence display device comprising:
at least one thin film transistor formed over a substrate;
a first insulating layer comprising organic resin formed over said thin film transistor;
a second insulating layer comprising DLC formed over said first insulating layer;
a third insulating layer comprising organic resin formed over said second insulating layer;
a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said third insulating layer.

E8
118. (Amended) An electroluminescence display device according to claim 117, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

119. (Amended) An electroluminescence display device according to claim 117, wherein said first insulating layer has a planarized surface.

sub
F1
120. (Amended) An electroluminescence display device according to claim 117, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

E9
sub
F1
121. (Amended) An electroluminescence display device comprising:
an active matrix region and a driver region formed over a substrate,
wherein said active matrix region comprises:
at least one thin film transistor;

transistor;
a first insulating layer comprising organic resin formed over said thin film
layer;
a second insulating layer comprising DLC formed over said first insulating
a pixel electrode formed over said second insulating layer, said pixel
electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said second insulating layer.

122. (Amended) An electroluminescence display device according to claim
117, wherein said organic resin is selected from the group consisting of polyimide,
polyimideamide, polyamide, acryl and epoxy.

123. (Amended) An electroluminescence display device according to claim
117, wherein said first insulating layer has a planarized surface.

124. (Amended) An electroluminescence display device according to claim
117, wherein said electroluminescence display device is incorporated into an electric
apparatus selected from the group consisting of a portable information terminal, a head
mount display, a portable telephone, a video camera and a projector.

125. (Amended) An electroluminescence display device comprising:
an active matrix region and a driver region over a substrate,
wherein said active matrix region comprises:
at least one thin film transistor;
a first insulating layer comprising silicon nitride formed over said thin film
transistor;
a second insulating layer comprising organic resin formed over said first
insulating layer;
a third insulating layer comprising DLC formed over said second insulting
layer;

E11
Con
and
a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said third insulating layer.

E12
File
126. (Amended) An electroluminescence display device according to claim 125, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

E13
File
127. (Amended) An electroluminescence display device according to claim 125, wherein said second insulating layer has a planarized surface.

E14
File
128. (Amended) An electroluminescence display device according to claim 125, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

E15
and
F1
129. (Amended) An electroluminescence display device comprising:
an active matrix region and a driver region over a substrate,
wherein said active matrix region comprises:
at least one thin film transistor;
a first insulating layer comprising organic resin formed over said thin film transistor;
a second insulating layer comprising DLC formed over said first insulating layer;
a third insulating layer comprising organic resin formed over said second insulating layer;
a pixel electrode formed over said third insulating layer, said pixel electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said third insulating layer.

130. (Amended) An electroluminescence display device according to claim 129, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

E16 131. (Amended) An electroluminescence display device according to claim 129, wherein said first insulating layer has a planarized surface.

132. (Amended) An electroluminescence display device according to claim 129, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

E17 133. (Amended) An electroluminescence display device comprising:
a switching element comprising at least one thin film transistor formed over a substrate;
a first insulating layer comprising organic resin formed over said switching element;
a second insulating layer comprising DLC formed over said first insulating layer;
a pixel electrode formed over said second insulating layer, said pixel electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said second insulating layer.

134. (Amended) An electroluminescence display device according to claim 133, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

135. (Amended) An electroluminescence display device according to claim 133, wherein said first insulating layer has a planarized surface.

136. (Amended) An electroluminescence display device according to claim 133, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.

137. (Amended) An electroluminescence display device comprising:
a switching element comprising at least one thin film transistor formed over a substrate;
a first insulating layer comprising organic resin [for providing] having a flattened upper surface, formed over said switching element;
a second insulating layer comprising DLC formed over said first insulating layer;
a pixel electrode formed over said second insulating layer, said pixel electrode electrically connected to said thin film transistor; and
a light-emitting layer formed over said second insulating layer.

138. (Amended) An electroluminescence display device according to claim 137, wherein said organic resin is selected from the group consisting of polyimide, polyimideamide, polyamide, acryl and epoxy.

139. (Amended) An electroluminescence display device according to claim 137, wherein said first insulating layer has a planarized surface.

140. (Amended) An electroluminescence display device according to claim 137, wherein said electroluminescence display device is incorporated into an electric apparatus selected from the group consisting of a portable information terminal, a head mount display, a portable telephone, a video camera and a projector.